

L Number	Hits	Search Text	DB	Time stamp
1	46532	sram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:01
2	157302	438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:02
3	3798	sram and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:03
4	440425	ARC or (antireflect\$3) or (anti adj reflect\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:06
5	314	(sram and 438/\$.ccls.) and (ARC or (antireflect\$3) or (anti adj reflect\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:06
6	460482	ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:09
7	664	(sram and 438/\$.ccls.) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:09
8	4402272	thermal or heat\$3 or anneal\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:10
9	556	((sram and 438/\$.ccls.) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride))) and (thermal or heat\$3 or anneal\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:12
10	770087	stress or void	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:12
11	221	((((sram and 438/\$.ccls.) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride))) and (thermal or heat\$3 or anneal\$4)) and (stress or void))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:18
12	15293	sti or (shallow adj trench adj isolation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:19
13	145	((((sram and 438/\$.ccls.) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride))) and (thermal or heat\$3 or anneal\$4)) and (sti or (shallow adj trench adj isolation)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:19
14	69	((((sram and 438/\$.ccls.) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride))) and (thermal or heat\$3 or anneal\$4)) and (stress or void)) and (sti or (shallow adj trench adj isolation))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:29

15	16	((("6136688") or ("6414376") or ("5883001") or ("5503882") or ("6221794") or ("5583077") or ("6468855") or ("6287962")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:31
16	4	((("6136688") or ("6414376") or ("5883001") or ("5503882") or ("6221794") or ("5583077") or ("6468855") or ("6287962")).PN.) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride)) and (thermal or heat\$3 or anneal\$4) ("6221794").PN.	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:37
17	2		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:40
18	243	embed\$3 adj SRAM	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:49
19	0	embed\$3 adj 1T-RAM	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 15:01
20	288	embed\$3 adj RAM	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:50
21	0	(embed\$3 adj RAM) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride)) and (sti or (shallow adj trench adj isolation))	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:50
23	1924	embed\$3 adj \$1RAM	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:52
24	96	(embed\$3 adj \$1RAM) and (ARC or (antireflect\$3) or (anti adj reflect\$3) or SiON or (silicon adj oxynitride)) and (sti or (shallow adj trench adj isolation))	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 14:52
25	8	1T-RAM	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/11 15:02

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